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Improved Structural Quality of AlN Grown on Sapphire by 3D/2D Alternation Growth

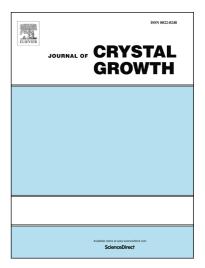
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